FDMS4435BZ

P-Channel PowerTrench® MOSFET

-30 V, -18 A, 20 mΩ

October 2014

Features

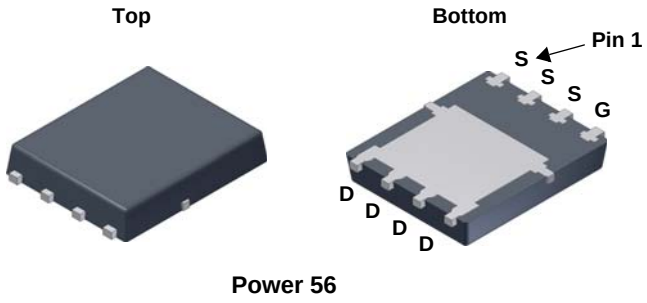
- Max $r_{DS(on)}$ = 20 mΩ at V_{GS} = -10 V, I_D = -9.0 A
- Max $r_{DS(on)}$ = 37 mΩ at V_{GS} = -4.5 V, I_D = -6.5 A
- Extended V_{GSS} range (-25 V) for battery applications
- High performance trench technology for extremely low $r_{DS(on)}$
- High power and current handling capability
- HBM ESD protection level >7 kV typical (Note 4)
- 100% UIL tested
- Termination is Lead-free and RoHS Compliant

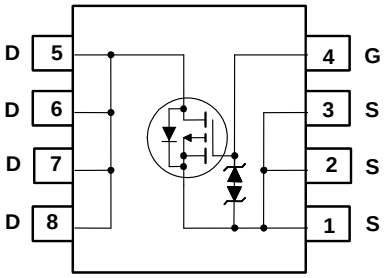
General Description

This P-Channel MOSFET is produced using Fairchild Semiconductor's advanced Power Trench® process that has been especially tailored to minimize the on-state resistance. This device is well suited for Power Management and load switching applications common in Notebook Computers and Portable Battery Packs.

Applications

- High side in DC-DC Buck Converters
- Notebook battery power management
- Load switch in Notebook





MOSFET Maximum Ratings T_A = 25 °C unless otherwise noted

Symbol	Parameter			Ratings	Units
V_{DS}	Drain to Source Voltage			-30	V
V_{GS}	Gate to Source Voltage			±25	V
I_D	Drain Current -Continuous (Package limited)	T_C = 25 °C		-18	A
	-Continuous (Silicon limited)	T_C = 25 °C		-35	
	-Continuous	T_A = 25 °C	(Note 1a)	-9.0	
	-Pulsed			-50	
E_{AS}	Single Pulse Avalanche Energy		(Note 3)	18	mJ
P_D	Power Dissipation	T_C = 25 °C		39	W
	Power Dissipation	T_A = 25 °C	(Note 1a)	2.5	
T_J, T_{STG}	Operating and Storage Junction Temperature Range			-55 to +150	°C

Thermal Characteristics

$R_{\theta JC}$	Thermal Resistance, Junction to Case	3.2	°C/W
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient (Note 1a)	50	

Package Marking and Ordering Information

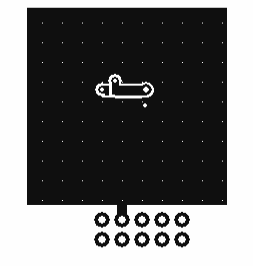
Device Marking	Device	Package	Reel Size	Tape Width	Quantity
FDMS4435BZ	FDMS4435BZ	Power 56	13 ”	12 mm	3000 units

Electrical Characteristics T_J = 25 °C unless otherwise noted

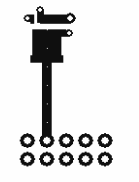
Symbol	Parameter	Test Conditions	Min	Typ	Max	Units
Off Characteristics						
BV_{DSS}	Drain to Source Breakdown Voltage	I_D = -250 μA, V_{GS} = 0 V	-30			V
$\frac{\Delta BV_{DSS}}{\Delta T_J}$	Breakdown Voltage Temperature Coefficient	I_D = -250 μA, referenced to 25 °C		-23		mV/°C
I_{DSS}	Zero Gate Voltage Drain Current	V_{DS} = -24 V, V_{GS} = 0 V			-1	μA
I_{GSS}	Gate to Source Leakage Current	V_{GS} = ±25 V, V_{DS} = 0 V			±10	μA
On Characteristics						
$V_{GS(th)}$	Gate to Source Threshold Voltage	V_{GS} = V_{DS}, I_D = -250 μA	-1.0	-1.9	-3.0	V
$\frac{\Delta V_{GS(th)}}{\Delta T_J}$	Gate to Source Threshold Voltage Temperature Coefficient	I_D = -250 μA, referenced to 25 °C		6		mV/°C
$r_{DS(on)}$	Static Drain to Source On Resistance	V_{GS} = -10 V, I_D = -9.0 A		15	20	mΩ
		V_{GS} = -4.5 V, I_D = -6.5 A		22	37	
		V_{GS} = -10 V, I_D = -9.0 A, T_J = 125 °C		21	28	
g_{FS}	Forward Transconductance	V_{DS} = -5 V, I_D = -9.0 A		25		S
Dynamic Characteristics						
C_{iss}	Input Capacitance	V_{DS} = -15 V, V_{GS} = 0 V, f = 1 MHz		1540	2050	pF
C_{oss}	Output Capacitance			290	390	pF
C_{rss}	Reverse Transfer Capacitance			260	385	pF
R_g	Gate Resistance			5		Ω
Switching Characteristics						
$t_{d(on)}$	Turn-On Delay Time	V_{DD} = -15 V, I_D = -9.0 A, V_{GS} = -10 V, R_{GEN} = 6 Ω		9	17	ns
t_r	Rise Time			10	18	ns
$t_{d(off)}$	Turn-Off Delay Time			35	56	ns
t_f	Fall Time			19	33	ns
Q_g	Total Gate Charge	V_{GS} = 0 V to -10 V; V_{DD} = -15 V, I_D = -9.0 A		34	47	nC
Q_g	Total Gate Charge	V_{GS} = 0 V to -4.5 V; V_{DD} = -15 V, I_D = -9.0 A		18	25	nC
Q_{gs}	Gate to Source Charge	V_{DD} = -15 V, I_D = -9.0 A		5		nC
Q_{gd}	Gate to Drain “Miller” Charge	V_{DD} = -15 V, I_D = -9.0 A		9		nC
Drain-Source Diode Characteristics						
V_{SD}	Source to Drain Diode Forward Voltage	V_{GS} = 0 V, I_S = -1.9 A (Note 2)		0.75	1.2	V
		V_{GS} = 0 V, I_S = -9.0 A (Note 2)		0.86	1.5	
t_{rr}	Reverse Recovery Time	I_F = -9.0 A, di/dt = 100 A/μs		25	39	ns
Q_{rr}	Reverse Recovery Charge			12	21	nC

Notes:

1. $R_{\theta JA}$ is determined with the device mounted on a 1 in^2 pad 2 oz copper pad on a 1.5 x 1.5 in. board of FR-4 material. $R_{\theta JC}$ is guaranteed by design while $R_{\theta CA}$ is determined by the user's board design.



a) 50 °C/W when mounted on a 1 in^2 pad of 2 oz copper



b) 125 °C/W when mounted on a minimum pad of 2 oz copper.

2. Pulse Test: Pulse Width < 300 μs, Duty cycle < 2.0%.
3. E_{AS} of 18 mJ is based on starting T_J = 25 °C, L = 1 mH, I_{AS} = -6 A, V_{DD} = -27 V, V_{GS} = -10 V. 100% tested at L = 0.3 mH, I_{AS} = -8 A.
4. The diode connected between the gate and source serves only as protection against ESD. No gate overvoltage rating is implied.

Typical Characteristics T_J = 25 °C unless otherwise noted

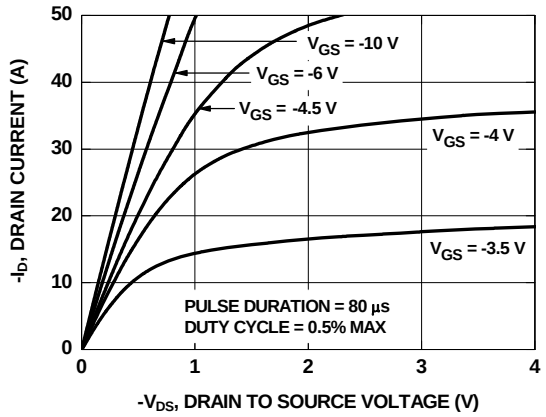


Figure 1. On-Region Characteristics

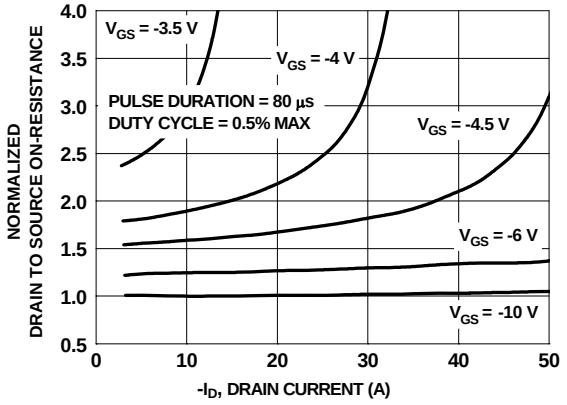


Figure 2. Normalized On-Resistance vs Drain Current and Gate Voltage

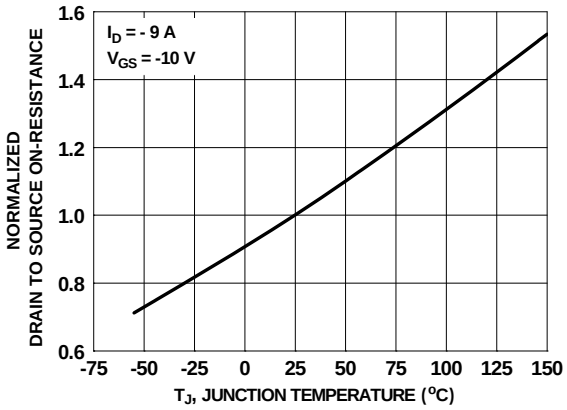


Figure 3. Normalized On-Resistance vs Junction Temperature

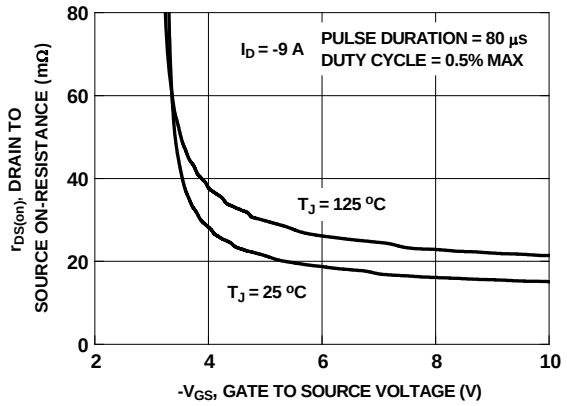


Figure 4. On-Resistance vs Gate to Source Voltage

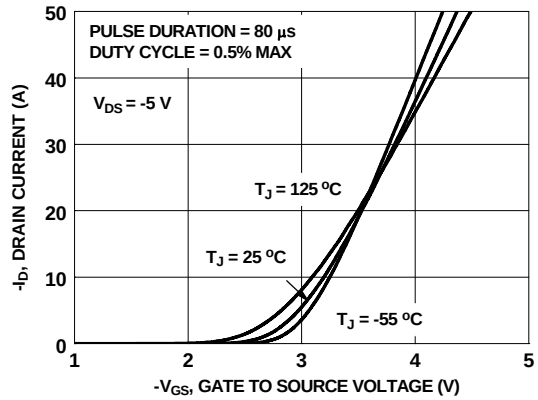


Figure 5. Transfer Characteristics

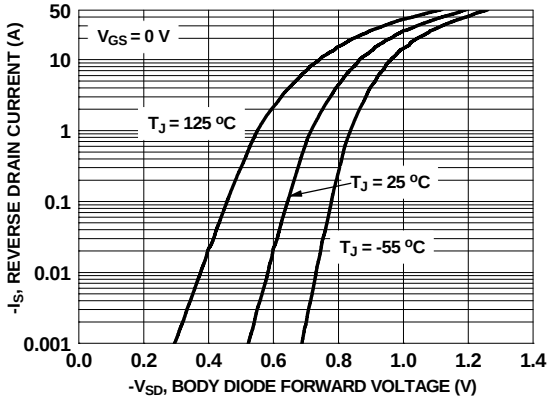


Figure 6. Source to Drain Diode Forward Voltage vs Source Current

Typical Characteristics T_J = 25 °C unless otherwise noted

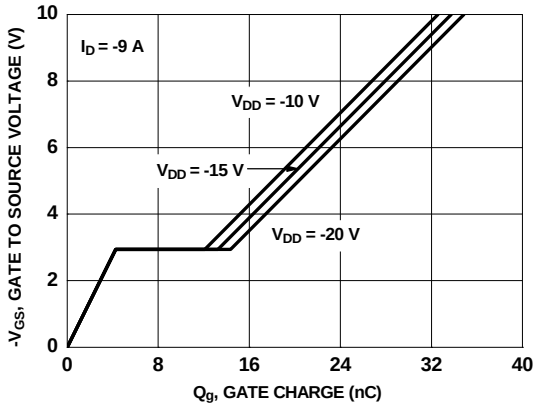


Figure 7. Gate Charge Characteristics

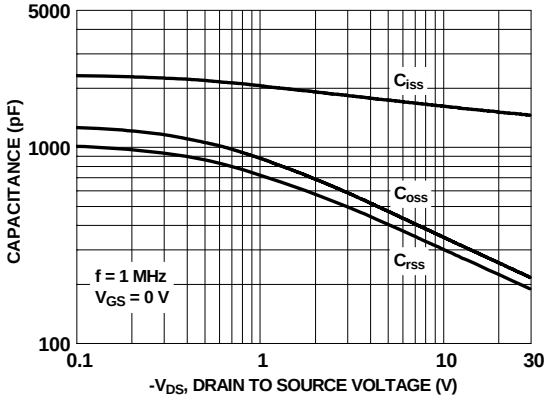


Figure 8. Capacitance vs Drain to Source Voltage

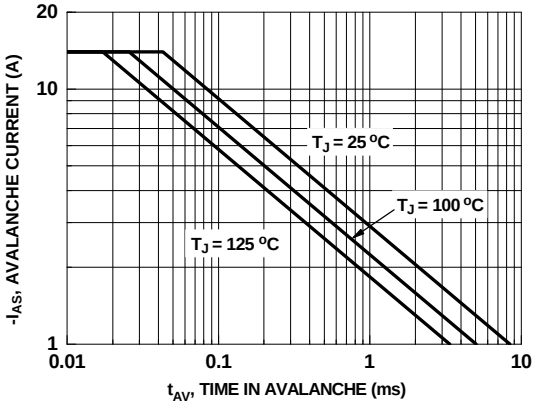


Figure 9. Unclamped Inductive Switching Capability

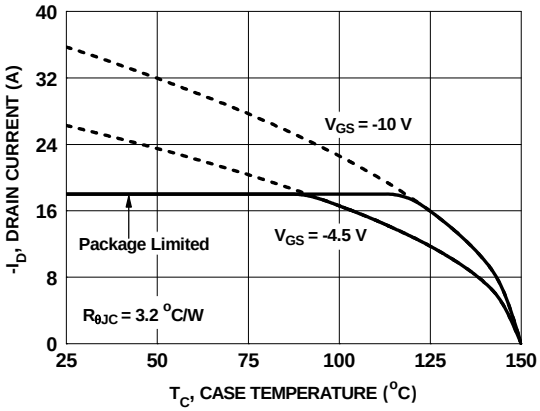


Figure 10. Maximum Continuous Drain Current vs Cate Temperature

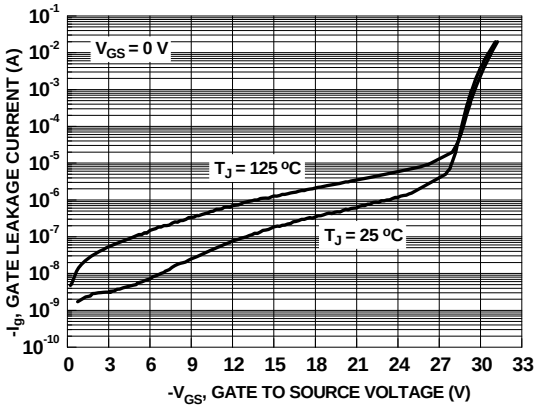


Figure 11. Gate Leakage Current vs Gate to Source Voltage

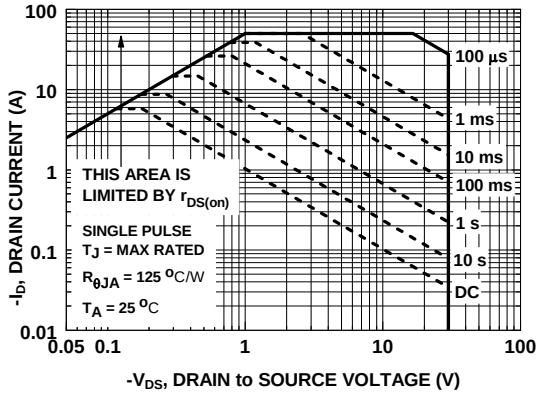


Figure 12. Forward Bias Safe Operating Area

Typical Characteristics T_J = 25 °C unless otherwise noted

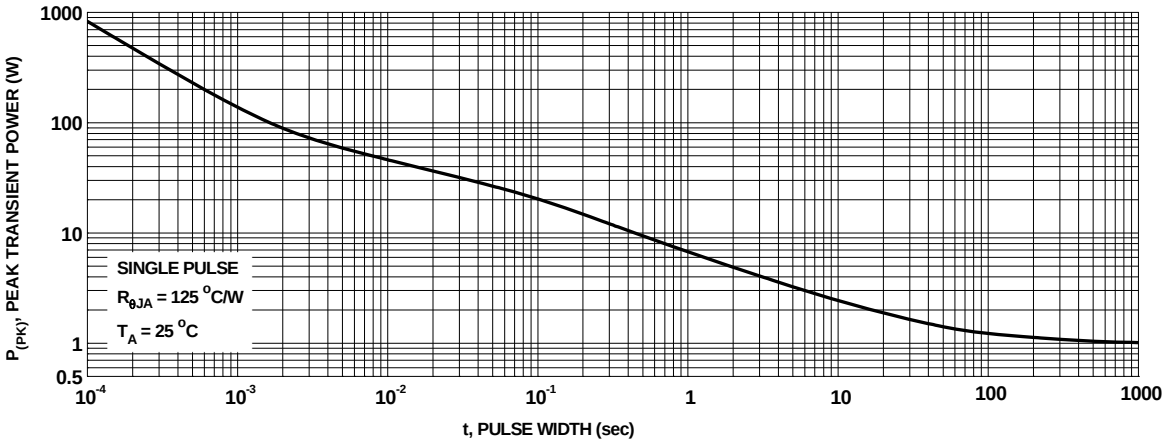


Figure 13. Single Pulse Maximum Power Dissipation

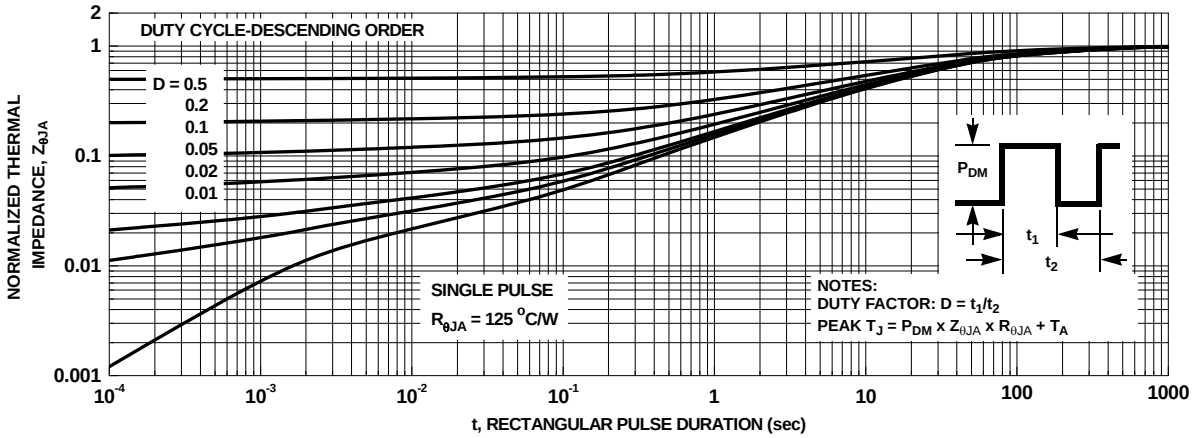
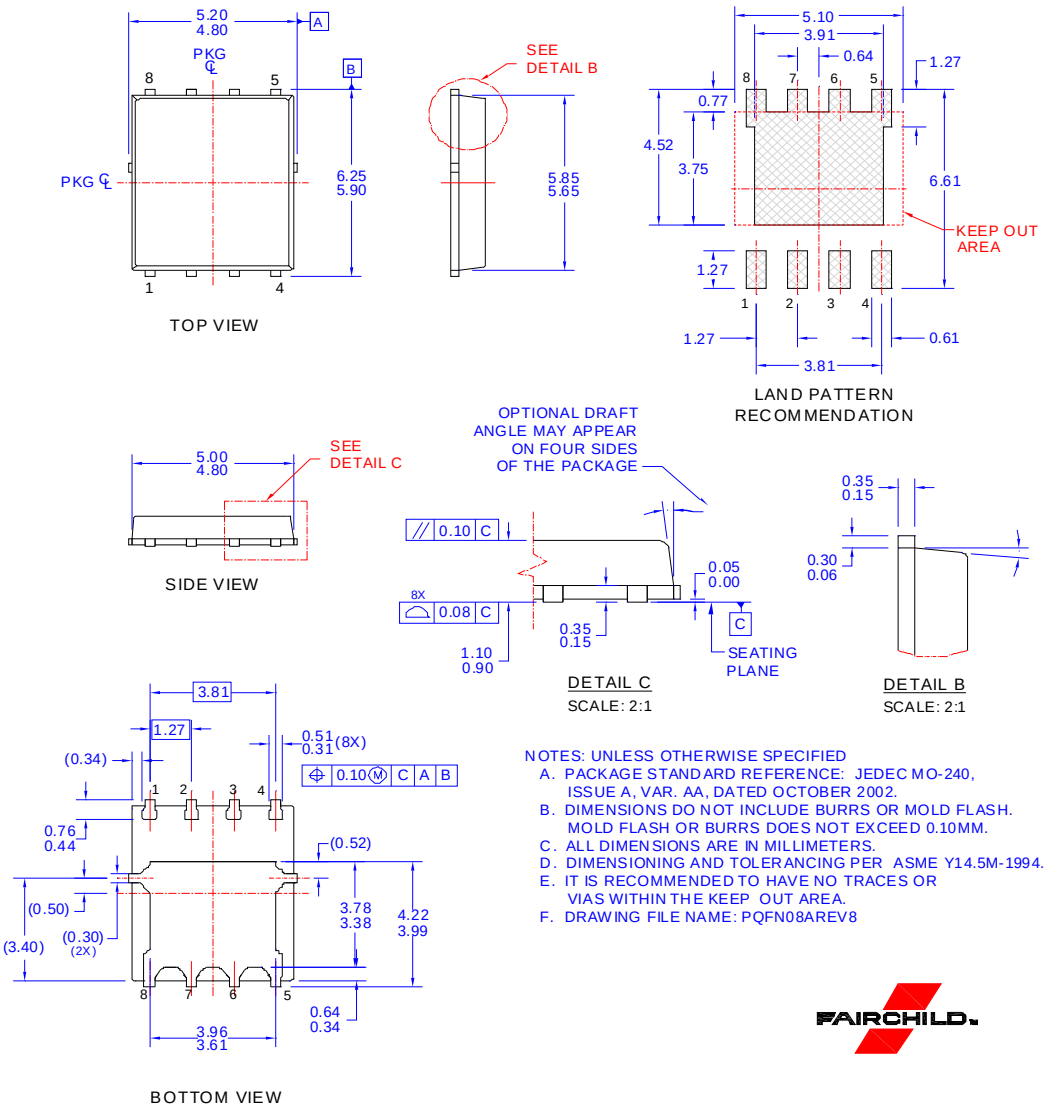


Figure 14. Junction-to-Ambient Transient Thermal Response Curve

Dimensional Outline and Pad Layout



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Datasheet Identification	Product Status	Definition
Advance Information	Formative / In Design	Datasheet contains the design specifications for product development. Specifications may change in any manner without notice.
Preliminary	First Production	Datasheet contains preliminary data; supplementary data will be published at a later date. Fairchild Semiconductor reserves the right to make changes at any time without notice to improve design.
No Identification Needed	Full Production	Datasheet contains final specifications. Fairchild Semiconductor reserves the right to make changes at any time without notice to improve the design.
Obsolete	Not In Production	Datasheet contains specifications on a product that is discontinued by Fairchild Semiconductor. The datasheet is for reference information only.

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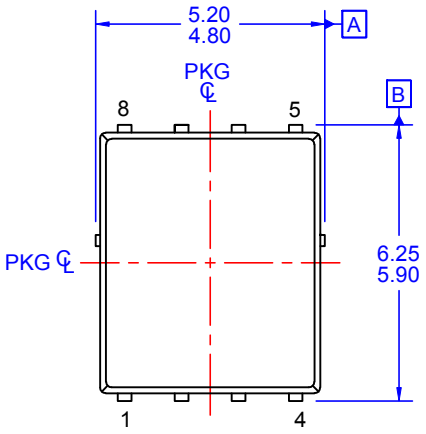
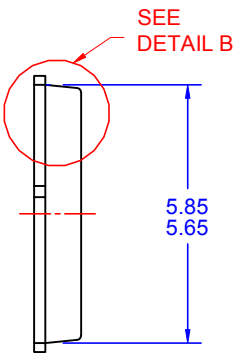
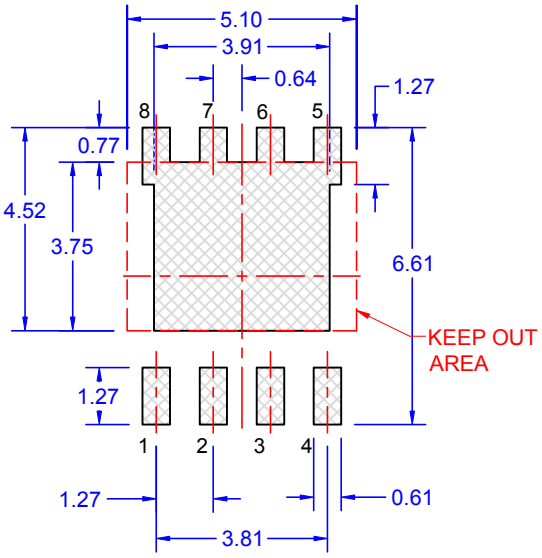
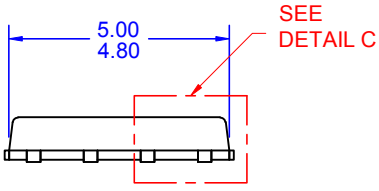


TOP VIEW

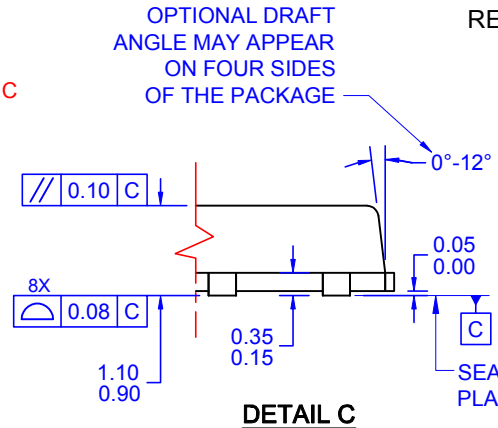




LAND PATTERN
RECOMMENDATION



SIDE VIEW



DETAIL C

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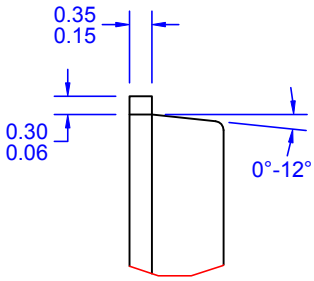
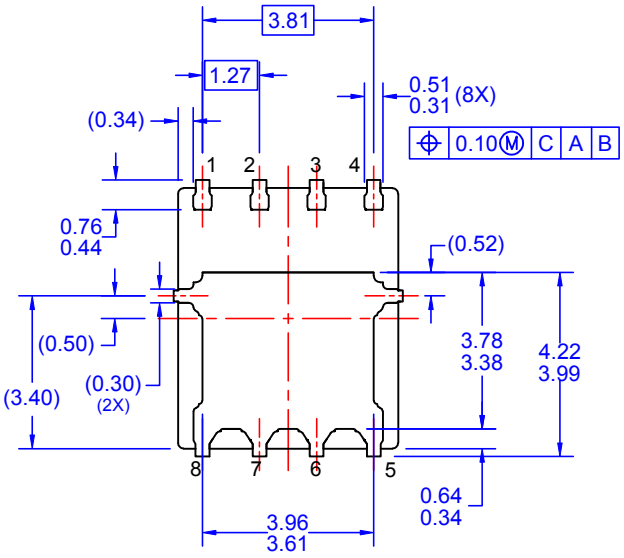


DETAIL B

SCALE: 2:1



BOTTOM VIEW

NOTES: UNLESS OTHERWISE SPECIFIED

A. PACKAGE STANDARD REFERENCE: JEDEC MO-240, ISSUE A, VAR. AA, DATED OCTOBER 2002.
B. DIMENSIONS DO NOT INCLUDE BURRS OR MOLD FLASH. MOLD FLASH OR BURRS DOES NOT EXCEED 0.10MM.
C. ALL DIMENSIONS ARE IN MILLIMETERS.
D. DIMENSIONING AND TOLERANCING PER ASME Y14.5M-1994.
E. IT IS RECOMMENDED TO HAVE NO TRACES OR VIAS WITHIN THE KEEP OUT AREA.
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SuperSOT™-3
SuperSOT™-6
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SyncFET™
Sync-Lock™
SYSTEM GENERAL®*
TinyBoost®
TinyBuck®
TinyCalc™
TinyLogic®
TINYOPTO™
TinyPower™
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Definition of Terms

Datasheet Identification	Product Status	Definition
Advance Information	Formative / In Design	Datasheet contains the design specifications for product development. Specifications may change in any manner without notice.
Preliminary	First Production	Datasheet contains preliminary data; supplementary data will be published at a later date. Fairchild Semiconductor reserves the right to make changes at any time without notice to improve design.
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